Initial Information Data Sheet

Inventor Information

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Postal Address Line Two

City:

State or Province:

Postal or Zip Code:

Citizenship Country:

Inventor One Given Name:

Family Name:

Name Suffix:

Postal Address Line One Postal Address Line Two

City:

State or Province:

Postal or Zip Code:

Citizenship Country:

Inventor One Given Name:

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Application Information

Title Line One: COMPOUND SEMICONDUCTOR
Title Line Two: SWITCHING DEVICE FOR HIGH
Title Line Three: FREQUENCY SWITCHING

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Formal Drawings?: YES Total Drawing Sheets: 9

Application Type: Utility Patent Docket Number: 492322001000

Representative Information

Representative Customer Number: 25227

Continuity Information

This application is a: > Application One:

Filing Date:

which is a:

>>Application Two:

Filing Date:

which is a:

>>>Application Three:

Filing Date:

Prior Foreign Applications

Foreign Application One: 2000-141387

Filing Date: May 15, 2000 Country: Japan

Country: Japan Priority Claimed: Yes